## **Supplementary information**

## Cationic pair substitution in LaAlO<sub>3</sub>:Mn<sup>4+</sup> for octahedral-tilting dependent zero-phonon line

Siyuan Li,<sup>a</sup> Chenyu Zhang,<sup>a</sup> Qi Zhu<sup>\*a</sup> and Ji-Guang Li<sup>\*b</sup>

<sup>a</sup>Key Laboratory for Anisotropy and Texture of Materials (Ministry of Education), School of Materials Science and Engineering, Northeastern University, Shenyang, Liaoning 110819, China

<sup>b</sup>Research Center for Functional Materials, National Institute for Materials Science, Namiki 1-1, Tsukuba, Ibaraki 305-0044, Japan

\*Corresponding authors:

Dr. Qi Zhu

Tel: +86-24-8367-2700

E-mail: zhuq@smm.neu.edu.cn

Dr. Ji-Guang Li

Tel: +81-29-860-4394 E-mail: <u>LI.Jiguang@nims.go</u>



Fig. S1 Rietveld refinement of LBAT:0.001Mn<sup>4+</sup> (*x*=0-0.2) and LYAG:0.001Mn<sup>4+</sup> (*y*=0-0.2).

**Table S1** The refined crystallographic data of LBAT:0.001Mn<sup>4+</sup> (*x*=0-0.2) and LYAG:0.001Mn<sup>4+</sup> (*y*=0-0.2)

Formula	а	β	V	R	R	R	$\chi^2$
	(Å)	(°)	(Å <sup>3</sup> )	(%)	(%)	$(\%)^{p}$	
LaAlO <sub>3</sub> :0.001Mn <sup>4+</sup>	3.7908(1)	90.0853(3)	54.4728(8)	5.13	6.83	4.86	1.33
<i>x</i> =0.05	3.7961(2)	90.0691(30)	54.703(10)	5.31	8.05	4.90	1.52
<i>x</i> =0.1	3.8018(1)	90.0610(38)	54.9507(40)	5.39	9.29	5.05	1.72
<i>x</i> =0.15	3.8092(2)	90.041(13)	55.2716(93)	5.14	9.27	5.61	1.80
<i>x</i> =0.2	3.8186(2)	90.012(20)	55.6830(67)	5.59	9.46	6.27	1.69
<i>y</i> =0.05	3.7949(1)	90.1253(27)	54.6514(56)	7.30	13.89	5.89	1.90
<i>y</i> =0.1	3.7975(1)	90.1593(6)	54.7654(18)	6.53	11.21	6.32	1.72
<i>y</i> =0.15	3.8015(2)	90.1842(12)	54.9352(64)	5.87	9.12	6.05	1.55
y=0.2	3.8023(2)	90.2135(28)	54.970(12)	6.38	9.73	6.66	1.53

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Atom	Wyck.	x	у	Z	$B_{\rm iso}$ (Å <sup>2</sup> )	Occ.
LaAlO <sub>3</sub> :0.0	01Mn <sup>4+</sup>		•			
La	1a	0	0	0	0.94(15)	1
Al	1a	0.5	0.5	0.5	0.69(16)	0.999
О	3b	0.5	0.5	0	1.48(16)	1
Mn	1a	0.5	0.5	0.5	0.69(16)	0.001
		0.00	0.0	0.00	0.03 (10)	0.001
x=0.05						
La	1a	0	0	0	1 45(30)	0.95
Al	1a	0 5	0 5	0.5	2 06(27)	0.949
0	3h	0.5	0.5	0	2.00(27) 2.77(38)	1
Ba	1a	0	0.5	0	1.45(30)	0.05
Ti	1a	0.5	0.5	0.5	2.06(27)	0.05
Mn	10	0.5	0.5	0.5	2.00(27) 2.06(27)	0.00
1111	14	0.5	0.5	0.5	2.00(27)	0.001
r = 0.1						
л U.1 Та	1a	0	0	Ο	0 559(64)	0.90
	1a 1a	0.5	0.5	0.5	0.337(07) 0.307(72)	0.20
	1a 3h	0.5	0.5	0.5	0.377(72) 0.712(81)	1
Ba	10	0.5	0.5	0	0.712(01) 0.550(64)	0.1
Da Ti	1a	05	05	05	0.339(04) 0.307(72)	0.1
11 Ma	1a	0.5	0.5	0.5	0.397(72)	0.1
IVIII	la	0.5	0.5	0.5	0.397(72)	0.001
x-0.13	1	0	0	0	0.740(61)	0.95
	1a	0	0	0	0.749(01)	0.83
Al	1a 21	0.5	0.5	0.5	0.043(80)	0.849
U D	3D	0.5	0.5	0	1.49(13)	
Ba T	1a	0	0	0	0.749(61)	0.15
	la	0.5	0.5	0.5	0.645(80)	0.15
Mn	la	0.5	0.5	0.5	0.645(80)	0.001
0.0						
x=0.2	1.	0	0	0	0 200(42)	0.0
	1a	0	0.5	0	0.388(43)	0.8
Al	1a	0.5	0.5	0.5	0.188(24)	0./99
0	36	0.5	0.5	0	0.583(68)	l
Ba	la	0	0	0	0.388(43)	0.2
Ti	la	0.5	0.5	0.5	0.188(24)	0.2
Mn	1a	0.5	0.5	0.5	0.188(24)	0.001
0.05						
<i>y</i> =0.05		0	0	~	1.10((0))	0.c <b>-</b>
La	la	0	0	0	1.19(60)	0.95
Al	la	0.5	0.5	0.5	3.00(12)	0.949
Ο	3b	0.5	0.5	0	2.64(17)	1
Y	1a	0	0	0	1.19(60)	0.05
Ga	1a	0.5	0.5	0.5	3.00(82)	0.05
Mn	1a	0.5	0.5	0.5	3.00(82)	0.001

**Table S2** Wyckoff lattice position (Wyck), atomic coordinates (x, y, z), isotropic displacement parameter  $(B_{iso})$  and atom occupancy (Occ.) for LBAT:0.001Mn<sup>4+</sup> (*x*=0-0.2) and LYAG:0.001Mn<sup>4+</sup> (*y*=0-0.2)

<i>y</i> =0.1						
La	1a	0	0	0	0.67(13)	0.90
Al	1a	0.5	0.5	0.5	0.28(17)	0.899
Ο	3b	0.5	0.5	0	2.21(25)	1
Y	1a	0	0	0	0.67(13)	0.1
Ga	1a	0.5	0.5	0.5	0.28(17)	0.1
Mn	1a	0.5	0.5	0.5	0.28(17)	0.001
<i>y</i> =0.15						
La	1a	0	0	0	0.20(20)	0.85
Al	1a	0.5	0.5	0.5	0.23(19)	0.849
Ο	3b	0.5	0.5	0	1.95(21)	1
Y	1a	0	0	0	0.20(20)	0.15
Ga	1a	0.5	0.5	0.5	0.23(19)	0.15
Mn	1a	0.5	0.5	0.5	0.23(19)	0.001
<i>y</i> =0.2						
La	1a	0	0	0	0.89(20)	0.80
Al	1a	0.5	0.5	0.5	0.80(20)	0.799
Ο	3b	0.5	0.5	0	3.00(24)	1
Y	1a	0	0	0	0.89(20)	0.2
Ga	1a	0.5	0.5	0.5	0.80(20)	0.2
Mn	1a	0.5	0.5	0.5	0.80(20)	0.001



Fig. S2 Calculated band structure (a) and partial density of states (b) for the  $La_{0.8}Ba_{0.2}Al_{0.8}Ti_{0.2}O_3$  host.



**Fig. S3** Decay curves of LBAT:0.001Mn<sup>4+</sup> (*x*=0-0.2) under excitation at 340 nm and monitoring at 726 nm at room temperature (a) and 77 K (b).



**Fig. S4** Decay curves of LYAG:0.001Mn<sup>4+</sup> (*y*=0-0.2) under excitation at 340 nm and monitoring at 726 nm at room temperature (a) and 77 K (b).





**Fig. S5** The  $In(I_0/I_K-1)$  vs 1/kT plot for determination of the activation energy of thermal quenching for (a) LaAlO<sub>3</sub>:0.001Mn<sup>4+</sup>, (b) x=0.2 and (c) y=0.2.